New Product

S1PB thru S1PM

Vishay General Semiconductor

High Current Density Surface Mount Glass-Passivated Rectifiers

FEATURES

- Very low profile typical height of 1.0 mm
- Ideal for automated placement
- Glass passivated chip junction
- · Low forward voltage drop
- Low thermal resistance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21
 definition
- Find out more about Vishay's Automotive Grade Product requirements at: <u>www.vishay.com/applications</u>

MECHANICAL DATA

Case: DO-220AA (SMP)

Molding compound meets UL 94 V-0 flammability rating

Base P/N-M3 - halogen-free and RoHS compliant, commercial grade

Base P/NHM3 - halogen-free and RoHS compliant, automotive grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test, HM3 suffix meets JESD 201 class 2 whisker test

Polarity: Color band denotes the cathode end

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)								
PARAMETER	SYMBOL	S1PB	S1PD	S1PG	S1PJ	S1PK	S1PM	UNIT
Device marking code		SB	SD	SG	SJ	SK	SM	
Maximum repetitive peak reverse voltage	V _{RRM}	100	200	400	600	800	1000	V
Maximum RMS voltage	V _{RMS}	70	140	280	420	560	700	V
Maximum DC blocking voltage	V _{DC}	100	200	400	600	800	1000	V
Average forward current	I _{F(AV)}	1.0						Α
Peak forward surge current 10 ms single half sine-wave superimposed on rated load	I _{FSM}	30					А	
Operating junction and storage temperature range	T _J , T _{STG}	- 55 to + 150						°C

eSMP[™] Series



DO-220AA (SMP)

PRIMARY CHARACTERISTICS						
I _{F(AV)} 1.0 A						
V _{RRM}	100 V to 1000 V					
I _R	1 μA					
V _F	0.95 V					
T _J max.	150 °C					

TYPICAL APPLICATIONS

General purpose, polarity protection, and rail-to-rail protection in both consumer and automotive applications.

Document Number: 88917 Revision: 07-Jul-09 For technical questions within your region, please contact one of the following: PDD-Americas@vishay.com, PDD-Asia@vishay.com, PDD-Europe@vishay.com



RoHS COMPLIANT HALOGEN FREE

Available



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ELECTRICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)										
PARAMETER	TEST CONDITIONS SYMBOL S1PB S1PD S1PG S1PJ S1PK				S1PK	S1PM	UNIT			
Maximum instantaneous forward voltage ⁽¹⁾	I _F = 1.0 A I _F = 1.0 A		V _F	1.1 0.95					V	
Maximum reverse current (2)	Rated V_{R}	T _J = 25 °C T _J = 125 °C	I _R	1.0 1.0 50 100					μA	
Typical reverse recovery time	l _F = 0.5 A, I _{rr} = 0.25 A	I _R = 1.0 A,	t _{rr}	1.8				μs		
Typical junction capacitance time	4.0 V, 1 MH	lz	CJ	6.0						pF

Notes:

 $^{(1)}$ Pulse test: 300 μs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: Pulse width \leq 40 ms

THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)								
PARAMETER	SYMBOL	L S1PB S1PD S1PG S1PJ S1PK S1PM U					UNIT	
Typical thermal resistance ⁽¹⁾	$egin{array}{c} R_{ heta JA} \ R_{ heta JL} \ R_{ heta JC} \end{array}$	105 15 20					°C/W	

Note:

⁽¹⁾ Thermal resistance from junction to ambient and junction to lead mounted on P.C.B. with 5.0 mm x 5.0 mm copper pad areas. $R_{\theta JC}$ is measured at the terminal of cathode band. $R_{\theta JC}$ is measured at the top center of the body

ORDERING INFORMATION (Example)									
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE					
S1PJ-M3/84A	0.024	84A	3000	7" diameter plastic tape and reel					
S1PJ-M3/85A	0.024	85A	10 000	13" diameter plastic tape and reel					
S1PJHM3/84A ⁽¹⁾	0.024	84A	3000	7" diameter plastic tape and reel					
S1PJHM3/85A ⁽¹⁾	0.024	85A	10 000	13" diameter plastic tape and reel					

Note:

⁽¹⁾ Automotive grade

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

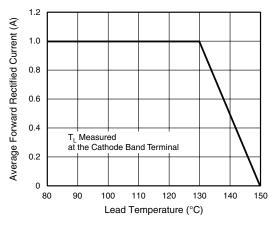


Figure 1. Maximum Forward Current Derating Curve

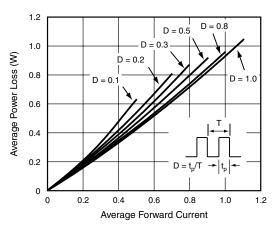


Figure 2. Forward Power Loss Characteristics



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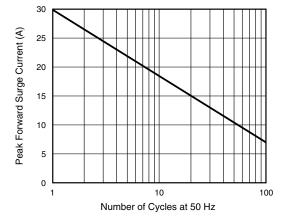


Figure 3. Maximum Non-Repetitive Peak Forward Surge Current

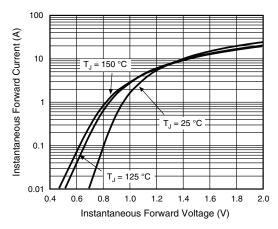


Figure 4. Typical Instantaneous Forward Characteristics

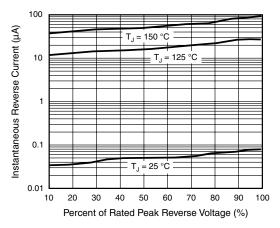


Figure 5. Typical Reverse Leakage Characteristics

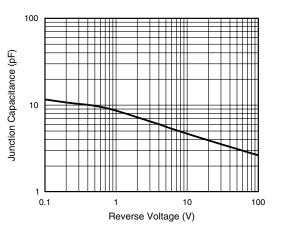


Figure 6. Typical Junction Capacitance

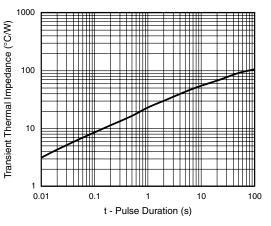
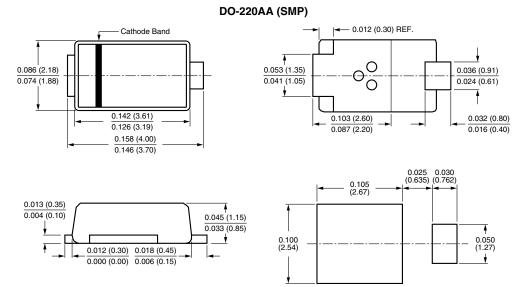


Figure 7. Typical Transient Thermal Impedance

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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)







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